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# Supertex inc. AP0332

# 8 P-Channel Latchable Power MOSFET Array

#### **Ordering Information**

V <sub>DD</sub>	R <sub>O(ON)</sub>	I <sub>O(ON)</sub>	I <sub>O(OFF)</sub>	Order Number/Package	
(max)	(max)	(min)	(max)	SO-16	Die
- <mark>320</mark> V	700Ω	-15mA	-1.0nA	AP0332CG	AP0332ND

\*Average current per channel, measured with all eight channels connected in parallel.

## Features

- Low drain to source leakage
- Interfaces directly to TTL and CMOS logic
- 8 independent channels
- Low crosstalk between channels
- Low power dissipation
- Freedom from secondary breakdown
- Serial data input
- On-chip decoder, latch with set and write disable circuitry

#### **Applications**

- High impedance/low leakage measurements for bare board testers
- High voltage piezoelectric transducer drivers
- High voltage electroluminescent panel drivers
- High voltage electrostatic array drivers
- General multi-channel driver arrays

## Absolute Maximum Ratings<sup>1</sup>

Off-state output voltage, V <sub>00</sub>	-320V
Logic supply voltage, V <sub>DD</sub>	-0.5V to +15V
Logic input levels, all inputs	-0.5V to V <sub>DD</sub>
Operating and storage temperature range	-55°C to +150°C
Soldering temperature <sup>2</sup>	300°C
Channel crosstalk	10mV/V

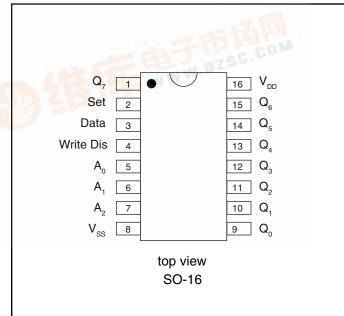
All voltages are referenced to V<sub>SS</sub>.
Distance of 1 6mm from case for 10 sec.

#### **General Description**

The Supertex AP0332 is an 8 P-Channel 320V common source power MOSFET array with a CMOS 8 bit addressable latch. The outputs are guaranteed to have very low leakage current. The outputs are addressed by logic inputs A0, A1, and A2. The addressed and unaddressed output can be turned on or off by the data, set, and write disable inputs.

The AP0332 is ideally suited for low leakage/high impedance measurements, providing excellent accuracy as well as resolution for automatic bare board test equipment and other applications.

#### Pin Configuration



Note: See Package Outline section for dimensions.

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# Electrical Characteristics (@ 25°C and V<sub>DD</sub> = 12V unless otherwise specified)

#### **DC Characteristics**

Parameter	Min	Тур	Max	Unit	Conditions
Off-State Output Current			-8.0	nA	V <sub>O</sub> = max. rating, 8 outputs connected in parallel
On-State Output Current	-15			mA	V <sub>O</sub> = 25V
On-State Output Resistance			700	Ω	l <sub>o</sub> = -10mA
Change in R <sub>O(ON)</sub> with High Temperature		0.8		%/°C	l <sub>o</sub> = -10mA
Quiescent Logic Supply Current		0.05	16.5	μA	
Input Low Voltage			3.5	V	
Input High Voltage	12			V	
Input Current			1.0	μΑ	
re referenced to V <sub>ss</sub> .	;0	LF	T	E·	
	On-State Output Current     On-State Output Resistance     Change in R <sub>O(ON)</sub> with High Temperature     Quiescent Logic Supply Current     Input Low Voltage     Input High Voltage     Input Current	On-State Output Current   -15     On-State Output Resistance   -15     Change in R <sub>O(ON)</sub> with High Temperature   -15     Quiescent Logic Supply Current   -15     Input Low Voltage   12     Input High Voltage   12	Off-State Output Current   -15     On-State Output Current   -15     On-State Output Resistance   -15     Change in R <sub>O(ON)</sub> with High Temperature   0.8     Quiescent Logic Supply Current   0.05     Input Low Voltage   12     Input High Voltage   12	Off-State Output Current-8.0On-State Output Current-15On-State Output Resistance700Change in R <sub>O(ON)</sub> with High Temperature0.8Quiescent Logic Supply Current0.05Input Low Voltage3.5Input High Voltage12Input Current1.0	Off-State Output Current-8.0nAOn-State Output Current-15mAOn-State Output Resistance700ΩChange in R <sub>O(ON)</sub> with High Temperature0.8%/°CQuiescent Logic Supply Current0.0516.5μAInput Low Voltage3.5VInput High Voltage12VInput Current1.0μA

#### **AC Characteristics**

Symbol	Parameter	Min	Тур	Max	Unit	Fig. 1*	Conditions
t <sub>D(ON)</sub>	Turn-On Delay Time		800		ns	1a	
t <sub>D(OFF)</sub>	Turn-Off Delay Time		800		ns	1b	
t <sub>r</sub>	Rise Time		200		ns	10	
t <sub>f</sub>	Fall Time		200		ns	11	
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time from Write Disable to Output		87		ns	2	V <sub>O</sub> = 25V, I <sub>O</sub> = -10mA
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time from Set to Output		87		ns	3	
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Time from Address to Output		107		ns	9	
t <sub>W</sub>	Minimum Pulse Width – Data		50	100	ns	4	
t <sub>w</sub>	Minimum Pulse Width – Address		100	200	ns	8	
t <sub>w</sub>	Minimum Pulse Width – Set		40	75	ns	5	
t <sub>s</sub>	Setup Time – Data to Write Disable	50			ns	6	
t <sub>H</sub>	Hold Time – Data to Write Disable	75			ns	7	
C <sub>IN</sub>	Input capacitance – Any Input		5.0	7.5	pF		

\*Refer to circled numbers on Timing Diagram (Figure 1).

Note:

1. All voltages are referenced to  $V_{ss}$ .

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Recommended Operating Conditions (For maximum reliability, nominal operating conditons should be selected so that operation is always within the following ranges.)

Symbol	Parameter	V <sub>DD</sub>	Min	Max	Unit
V <sub>DD</sub>	Logic supply voltage		10.0	13.2	V
Vo	Output Voltage referenced to $V_{\text{DD}}$		0	-320	V
V <sub>IH</sub>	Input High Voltage	12V	V <sub>DD</sub> - 2	V <sub>DD</sub>	V
V <sub>IL</sub>	Input Low Voltage	12V	0	2.0	V
T <sub>A</sub>	Operating Free-Air Temperature		0	70	О°

Note:

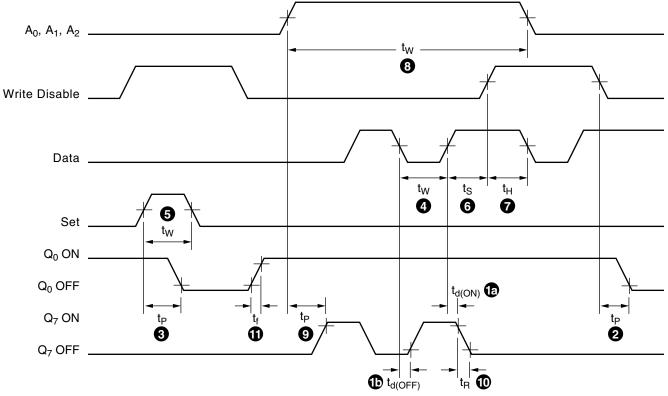
1. All voltages are referenced to V<sub>ss</sub>.



#### **Mode Selection**

Data	Write Disable	Set	Addressed Output	Unaddressed Outputs
H L	L	L	Off On	Holdspriv.
H L	Н	L	Holdspriv.	Holdspriv.
H L	L	Н	Off On	Off
H	н	Н	Off	Off

# **Timing Diagram**



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